

TC74LVX00F, TC74LVX00FN, TC74LVX00FT

Quad 2-Input NAND Gate

The TC74LVX00F/FN/FT is a high-speed CMOS 2-input NAND gate fabricated with silicon gate CMOS technology. Designed for use in 3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

This device is suitable for low-voltage and battery operated systems.

The internal circuit is composed of 3 stages including buffer output, which provide high noise immunity and stable output.

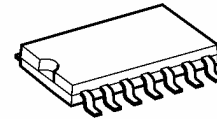
An input protection circuit ensures that 0 to 5.5V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

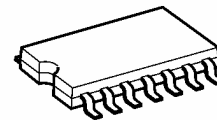
- High-speed: $t_{pd} = 4.1 \text{ ns (typ.)}$ ($V_{CC} = 3.3 \text{ V}$)
- Low power dissipation: $I_{CC} = 2 \mu\text{A (max)}$ ($T_a = 25^\circ\text{C}$)
- Input voltage level: $V_{IL} = 0.8 \text{ V (max)}$ ($V_{CC} = 3 \text{ V}$)
 $V_{IH} = 2.0 \text{ V (min)}$ ($V_{CC} = 3 \text{ V}$)
- Power-down protection provided on all inputs
- Balanced propagation delays: $t_{pLH} \approx t_{pHL}$
- Low noise: $V_{OLP} = 0.5 \text{ V (max)}$
- Pin and function compatible with 74HC00

Note: xxxFN (JEDEC SOP) is not available in Japan.

TC74LVX00F

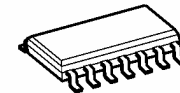


SOP14-P-300-1.27A



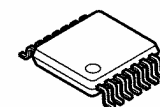
SOP14-P-300-1.27

TC74LVX00FN



SOL14-P-150-1.27

TC74LVX00FT

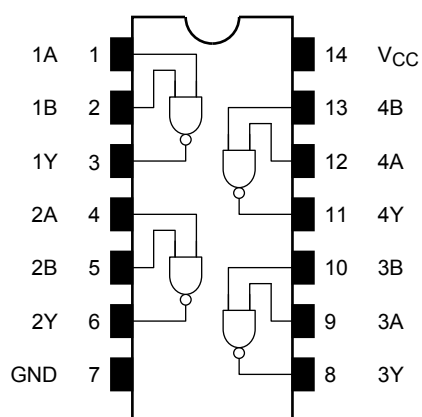


TSSOP14-P-0044-0.65A

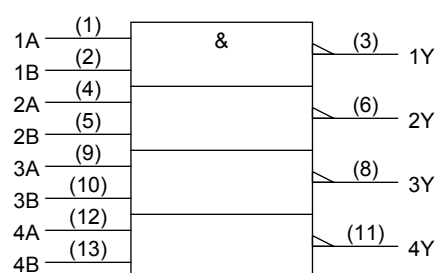
Weight

SOP14-P-300-1.27A	: 0.18 g (typ.)
SOP14-P-300-1.27	: 0.18 g (typ.)
SOL14-P-150-1.27	: 0.12 g (typ.)
TSSOP14-P-0044-0.65A	: 0.06 g (typ.)

Pin Assignment (top view)



IEC Logic Symbol



Truth Table

Input		Output
A	B	Y
L	L	H
L	H	H
H	L	H
H	H	L

Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	-0.5 to 7.0	V
DC input voltage	V_{IN}	-0.5 to 7.0	V
DC output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input diode current	I_{IK}	-20	mA
Output diode current	I_{OK}	± 20	mA
DC output current	I_{OUT}	± 25	mA
DC V_{CC} /ground current	I_{CC}	± 50	mA
Power dissipation	P_D	180	mW
Storage temperature	T_{stg}	-65 to 150	$^{\circ}C$

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2.0 to 3.6	V
Input voltage	V_{IN}	0 to 5.5	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Operating temperature	T_{opr}	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 100	ns/V

Note: The recommended operating conditions are required to ensure the normal operation of the device.
Unused inputs must be tied to either VCC or GND.

Electrical Characteristics
DC Characteristics

Characteristics		Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit	
					V _{CC} (V)	Min	Typ.	Max	Min		Max
Input voltage	H-level	V _{IH}	—	2.0	1.5	—	—	1.5	—	V	
				3.0	2.0	—	—	2.0	—		
				3.6	2.4	—	—	2.4	—		
	L-level	V _{IL}	—	2.0	—	—	0.5	—	0.5		
				3.0	—	—	0.8	—	0.8		
				3.6	—	—	0.8	—	0.8		
Output voltage	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	2.0	1.9	2.0	—	1.9	—	V
				I _{OH} = -50 μA	3.0	2.9	3.0	—	2.9	—	
				I _{OH} = -4 mA	3.0	2.58	—	—	2.48	—	
	L-level	V _{OL}	V _{IN} = V _{IH}	I _{OL} = 50 μA	2.0	—	0	0.1	—	0.1	
				I _{OL} = 50 μA	3.0	—	0	0.1	—	0.1	
				I _{OL} = 4 mA	3.0	—	—	0.36	—	0.44	
Input leakage current		I _{IN}	V _{IN} = 5.5 V or GND	3.6	—	—	±0.1	—	±1.0	μA	
Quiescent supply current		I _{CC}	V _{IN} = V _{CC} or GND	3.6	—	—	2.0	—	20.0	μA	

AC Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = −40 to 85°C		Unit
			V _{CC} (V)	C _L (pF)	Min	Typ.	Max	Min	Max	
Propagation delay time	t _{pLH}	—	2.7	15	—	5.4	10.1	1.0	12.5	ns
				50	—	7.9	13.6	1.0	16.0	
	t _{pHL}		3.3 ± 0.3	15	—	4.1	6.2	1.0	7.5	
				50	—	6.6	9.7	1.0	11.0	
Output to output skew	t _{osLH}	(Note 1)	2.7	50	—	—	1.5	—	1.5	ns
	t _{osHL}		3.3 ± 0.3	50	—	—	1.5	—	1.5	
Input capacitance	C _{IN}	(Note 2)			—	4	10	—	10	pF
Power dissipation capacitance	C _{PD}	(Note 3)			—	19	—	—	—	pF

Note 1: Parameter guaranteed by design.

$$(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$$

Note 2: Parameter guaranteed by design.

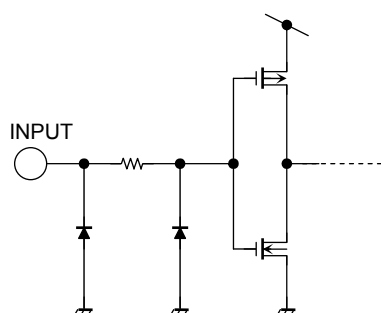
Note 3: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation:

$$I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4 \text{ (per gate)}$$

Noise Characteristics (Ta = 25°C, input: $t_r = t_f = 3$ ns, C_L = 50 pF)

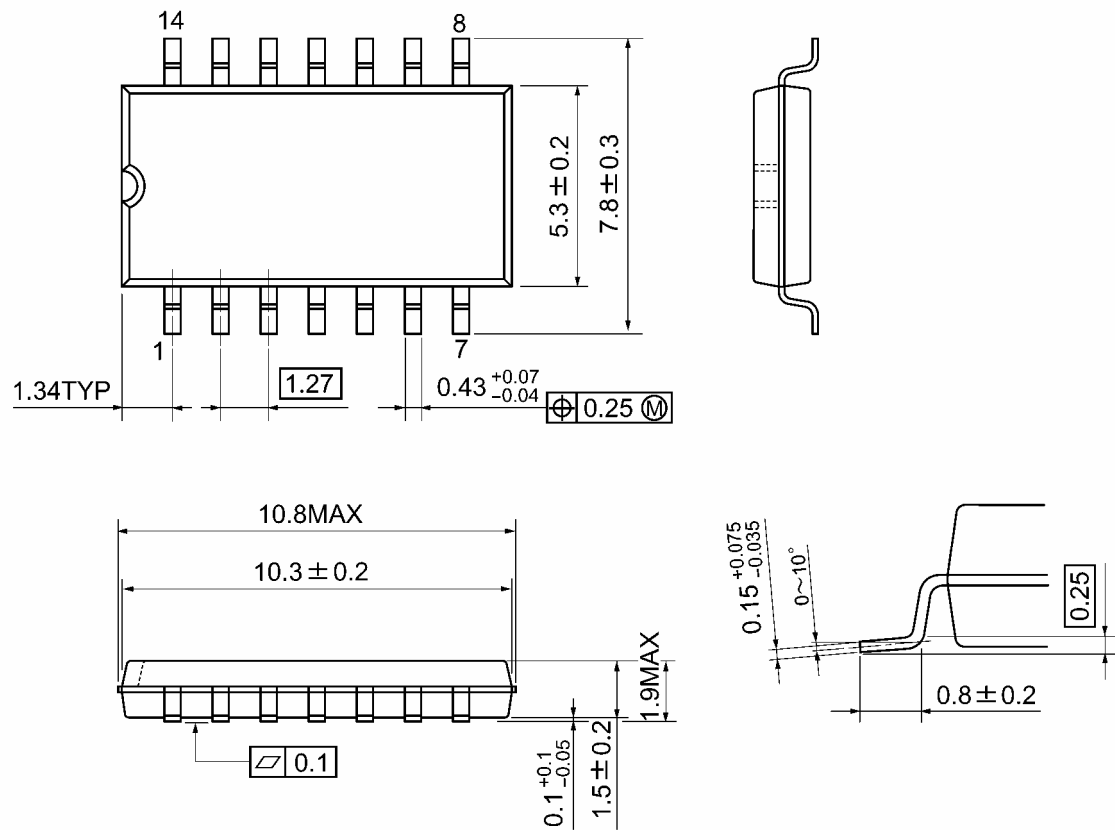
Characteristics	Symbol	Test Condition		Typ.	Limit	Unit
			V _{CC} (V)			
Quiet output maximum dynamic V _{OL}	V _{OLP}	—	3.3	0.3	0.5	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	—	3.3	−0.3	−0.5	V
Minimum high level dynamic input voltage V _{IH}	V _{IHD}	—	3.3	—	2.0	V
Maximum low level dynamic input voltage V _{IL}	V _{ILD}	—	3.3	—	0.8	V

Input Equivalent Circuit

Package Dimensions

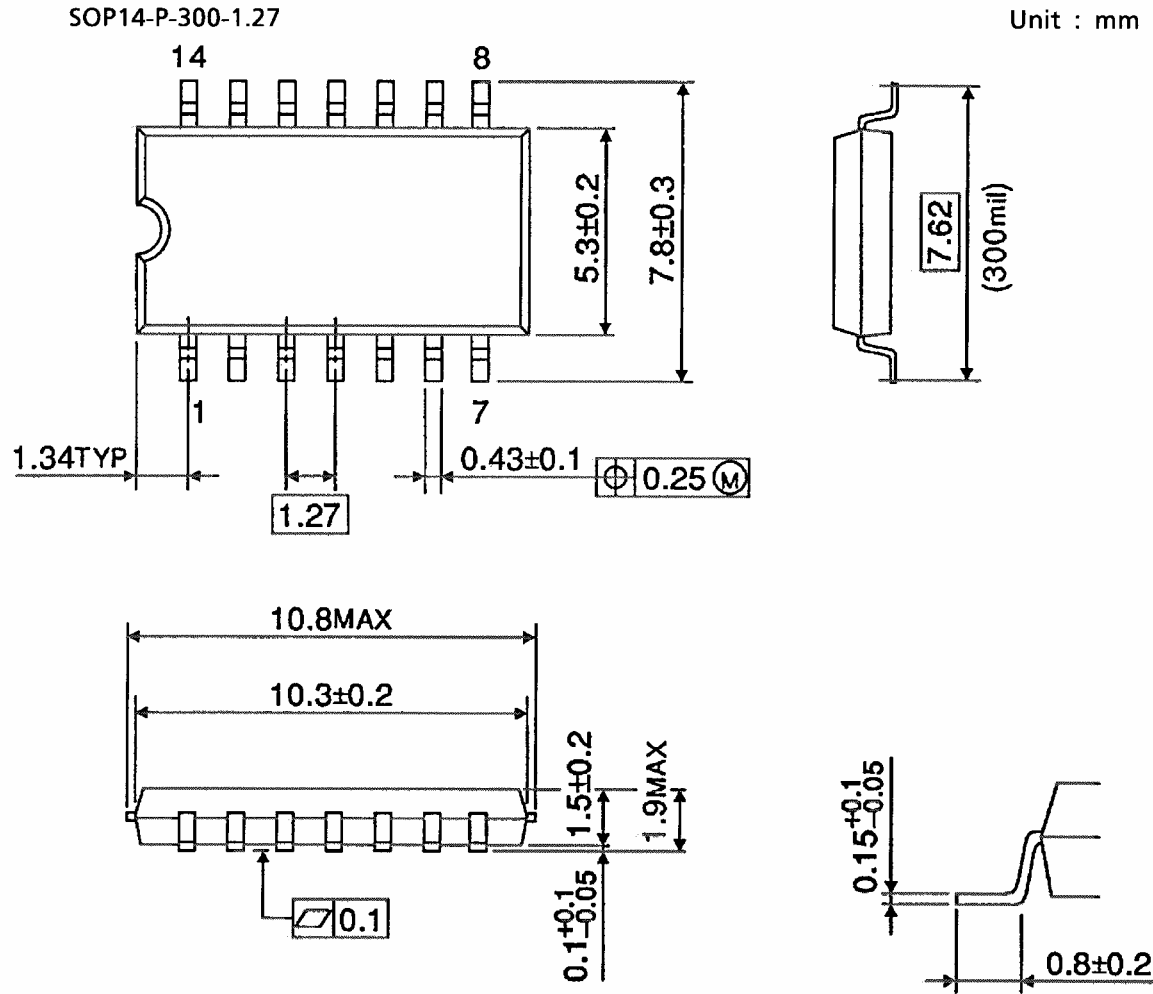
SOP14-P-300-1.27A

Unit: mm



Weight: 0.18 g (typ.)

Package Dimensions

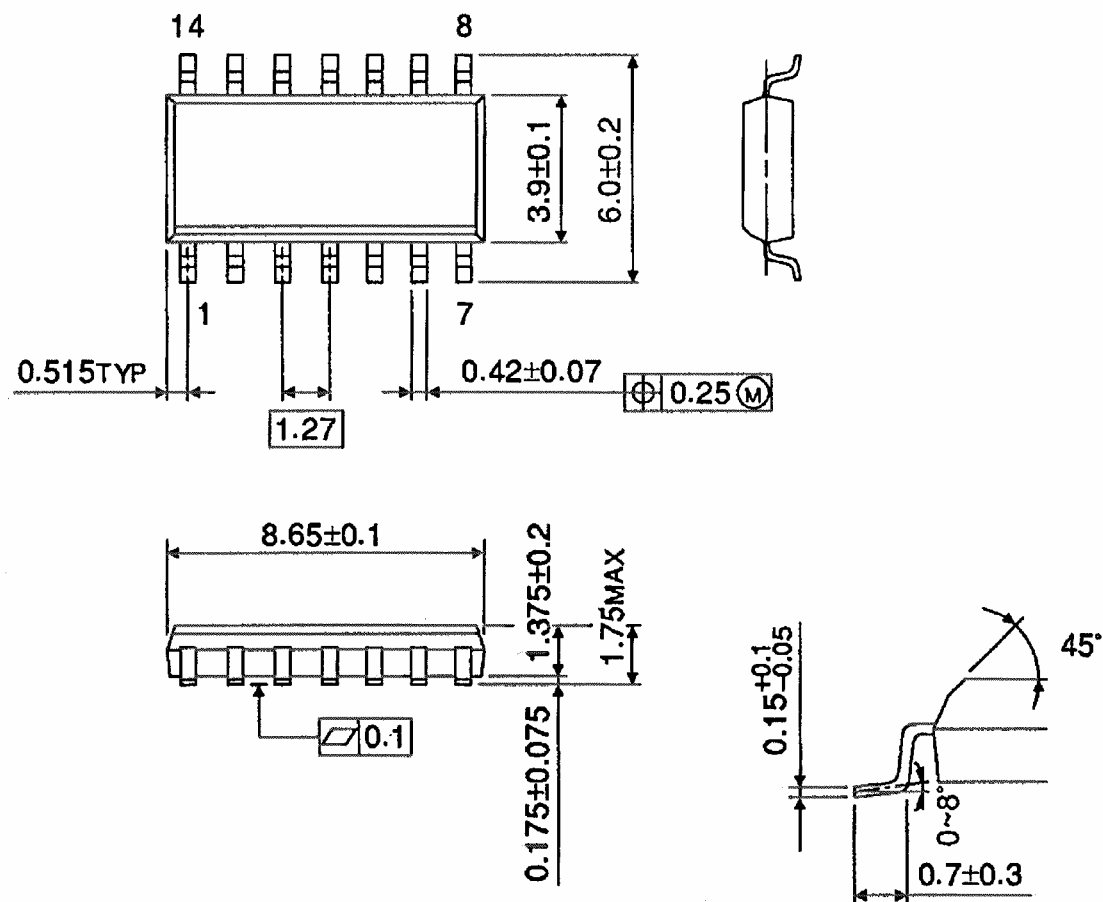


Weight: 0.18 g (typ.)

Package Dimensions (Note)

SOL14-P-150-1.27

Unit : mm



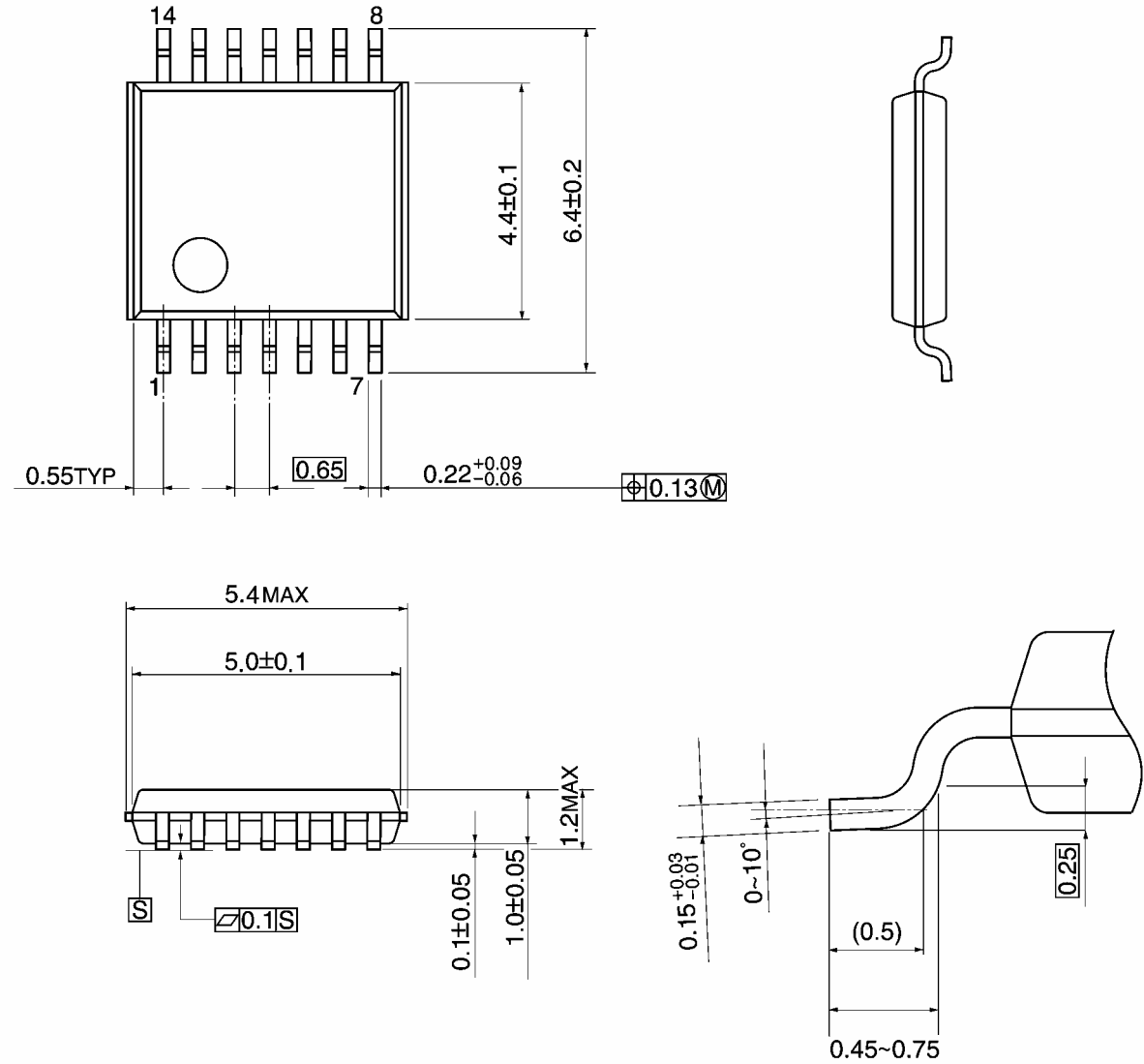
Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

Package Dimensions

TSSOP14-P-0044-0.65A

Unit: mm



Weight: 0.06 g (typ.)

Note: Lead (Pb)-Free Packages**SOP14-P-300-1.27A SOL14-P-150-1.27 TSSOP14-P-0044-0.65A****RESTRICTIONS ON PRODUCT USE**

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